Diode Semiconductor Device - Page 1 of 1



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Inclosure Mate	erial:
Glass	
Overall Lengtl	h:
0.300 inches	
Terminal Leng	gth:
1.000 inches	
Overall Diame	eter:
0.107 inches	
Joint Electron	ic Device Engineering Council/jedec/case Outline Designation:
Do-7	
Mounting Met	hod:
Terminal	
Features Prov	vided:
Hermetically se	ealed case
Semiconducto	or Material:
Silicon	
Voltage Rating	g In Volts Per Characteristic:
10.0 regulator	r voltage
Current Rating	g Per Characteristic:
20.00 milliamp	eres source cutoff current horsepower metric
Power Rating	Per Characteristic:
500.0 milliwatte	s small-signal input power, common-collector preset
Maximum Ope	erating Tempurature Per Measurement Point:
200.0 degrees	celsius junction
Terminal Type	e And Quantity:
2 uninsulated v	vire lead
Shelf Life:	
N/a	
Unit Of Measu	ire:
Demilitarizatio	on:
No	
Fiig:	
A110a0	